Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-085-3421

Metal	
	all Length:
	) inches
	inal Length:
	) inches
	all Diameter:
0.500	) inches
End /	Application:
	r threat emiter an/mst-t1
Mour	nting Method:
Term	inal
Featu	ures Provided:
Herm	etically sealed case
Critic	ality Code Justification:
Feat	
Semi	conductor Material:
Silico	n
Volta	ge Rating In Volts Per Characteristic:
1000	0.0 reverse voltage, peak
Curre	ent Rating Per Characteristic:
5.00 a	amperes source cutoff current preset
Maxi	mum Operating Tempurature Per Measurement Point:
150.0	) degrees celsius ambient air
Spec	ial Features:
Weap	oon system essential; junction pattern arrangement: npn
	inal Type And Quantity:
	nsulated wire lead
	Life:
N/a	
Unit	Of Measure:
	litarization:
No	
Fiig:	